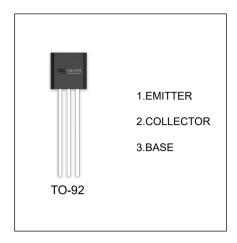


2SC1318A TRANSISTOR (NPN)

FEATURES

· Collector Output Capacitance : Cob=11 pF (TYP),20 pF (MAX)



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
2SC1318A	TO-92	Bulk	1000pcs/Bag
2SC1318A-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	80	V
V _{CEO}	Collector-Emitter Voltage	70	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current -Continuous	0.5	А
P _D	Collector Power Dissipation	750	mW
R _{0 JA}	Thermal Resistance from Junction to Ambient	167	°C /W
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C



$\rm T_a = 25 \, ^{\circ} \! C$ unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =10μA,I _E =0	80			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =2mA,I _B =0	70			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =10μA,I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =20V,I _E =0			0.1	μA
DO	h _{FE(1)}	V _{CE} =10V,I _C =150mA	85		340	
DC current gain	h _{FE(2)}	V _{CE} =10V,I _C =500mA	40			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =300mA,I _B =30mA			0.6	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C =300mA,I _B =30mA			1.5	V
Transition frequency	f _T	V _{CE} =10V,I _C =50mA,f=200MHz		120		MHz
Collector output capacitance	Cob	V _{CB} =10V,I _E =0,f=1MHz		11	20	pF

CLASSIFICATION OF h_{FE(1)}

Rank	Q	R	S
Range	85-170	120-240	170-340